JUL 18 2006

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of:		)
Inventors:	Li et al.	) ATTORNEY FILE NO.: ) SLA0845
Serial No.:	10/761,704	) ) Examiner: Erdem, Fazli
Filed:	January 21, 2004	) Customer No.: 55,286
Title:	ULTRA-SHALLOW METAL OXIDE SURFACE CHANNEL MOS TRANSISTOR	) Group Art: 2826
		Confirmation No.: 3680

MAIL STOP AMENDMENTS Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## **CERTIFICATION UNDER 37 CFR § 1.8**

I hereby certify that this correspondence is being facsimile transmitted to the US Patent and Trademark Office, fax No. 571 273 8800, on this date 7/18/2006.

Date

7/18/2006

Signature

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## RESPONSE TO RESTRICTION REQUIREMENT

The present communication is responsive to a restriction requirement mailed July 13, 2005, for the above-mentioned application.

The Applicant elects to pursue the Group II Claims, claims 4-8, 11-12, and 24, drawn to a method for making a semiconductor device.

The Applicant cancels claims 16-20 and 23 without traverse.

Respectfully submitted,

Date: 7/18/2006

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